

## **Microcontroller Series for Industrial Applications**

ARM® Cortex®-M0
32-bit processor core

## **About this Document**

This datasheet is addressed to embedded hardware and software developers. It provides the reader with detailed descriptions about the ordering designations, available features, electrical and physical characteristics of the XMC1100 series devices.

The document describes the characteristics of a superset of the XMC1100 series devices. For simplicity, the various device types are referred to by the collective term XMC1100 throughout this document.

#### **XMC1000 Family User Documentation**

The set of user documentation includes:

#### · Reference Manual

describes the functionality of the superset of devices.

#### Datasheets

 list the complete ordering designations, available features and electrical characteristics of derivative devices.

#### Errata Sheets

- list deviations from the specifications given in the related Reference Manual or Datasheets. Errata Sheets are provided for the superset of devices.

Attention: Please consult all parts of the documentation set to attain consolidated knowledge about your device.

Application related guidance is provided by Users Guides and Application Notes.

Please refer to http://www.infineon.com/xmc1000 to get access to the latest versions of those documents.

## **Microcontroller Series for Industrial Applications**



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#### 1 Summary of Features

## **1** Summary of Features

The XMC1100 devices are members of the XMC1000 Family of microcontrollers based on the ARM Cortex-M0 processor core. The XMC1100 series devices are designed for general purpose applications.

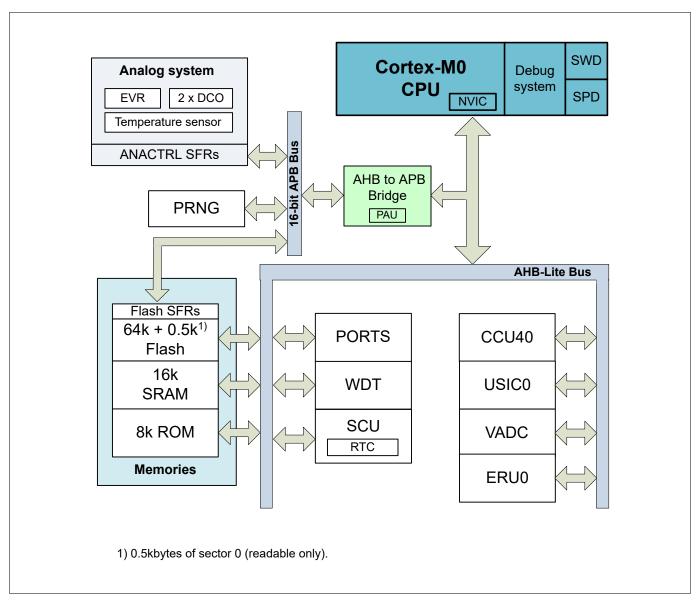


Figure 1 System Block Diagram

#### **CPU Subsystem**

- CPU Core
  - High-performance 32-bit ARM Cortex-M0 CPU
  - Most 16-bit Thumb and subset of 32-bit Thumb2 instruction set
  - Single cycle 32-bit hardware multiplier
  - System timer (SysTick) for Operating System support
  - Ultra low power consumption
- Nested Vectored Interrupt Controller (NVIC)
- Event Request Unit (ERU) for processing of external and internal service requests

#### **Microcontroller Series for Industrial Applications**



#### 1 Summary of Features

#### **On-Chip Memories**

- 8 kbytes on-chip ROM
- 16 kbytes on-chip high-speed SRAM
- up to 64 kbytes on-chip Flash program and data memory

#### **On-Chip Peripherals**

- Two Universal Serial Interface Channels (USIC), usable as UART, double-SPI, quad-SPI, IIC, IIS and LIN interfaces
- A/D Converters
  - up to 12 analog input pins and channels
  - 12-bit analog to digital converter
- Capture/Compare Units 4 (CCU4) for use as general purpose timers
- Window Watchdog Timer (WDT) for safety sensitive applications
- Real Time Clock module with alarm support (RTC)
- System Control Unit (SCU) for system configuration and control
- Pseudo random number generator (PRNG) for fast random data generation
- Temperature Sensor (TSE)

#### Input/Output Lines With Individual Bit Controllability

- Tri-stated in input mode
- Push/pull or open drain output mode
- Configurable pad hysteresis

#### **Debug System**

- Access through the standard ARM serial wire debug (SWD) or the single pin debug (SPD) interface
- A breakpoint unit (BPU) supporting up to 4 hardware breakpoints
- A watchpoint unit (DWT) supporting up to 2 watchpoints

#### 1.1 **Ordering Information**

The ordering code for an Infineon microcontroller provides an exact reference to a specific product. The code "XMC1<DDD>-<Z><PPP><T><FFFF>" identifies:

- <DDD> the derivatives function set
- <Z> the package variant
  - T: TSSOP
  - Q: VQFN
- <PPP> package pin count
- <T> the temperature range:
  - F: -40°C to 85°C
  - X: -40°C to 105°C
- <FFFF> the Flash memory size

For ordering codes for the XMC1100 please contact your sales representative or local distributor.

This document describes several derivatives of the XMC1100 series, some descriptions may not apply to a specific product. Please see Table 1.

For simplicity the term **XMC1100** is used for all derivatives throughout this document.



## 1 Summary of Features

## 1.2 Device Types

These device types are available and can be ordered through Infineon's direct and/or distribution channels.

Table 1 Synopsis of XMC1100 Device Types

Derivative	Package	Flash Kbytes	SRAM Kbytes
XMC1100-T016F0008	PG-TSSOP-16-8	8	16
XMC1100-T016F0016	PG-TSSOP-16-8	16	16
XMC1100-T016F0032	PG-TSSOP-16-8	32	16
XMC1100-T016F0064	PG-TSSOP-16-8	64	16
XMC1100-T016X0016	PG-TSSOP-16-8	16	16
XMC1100-T016X0032	PG-TSSOP-16-8	32	16
XMC1100-T016X0064	PG-TSSOP-16-8	64	16
XMC1100-T038F0016	PG-TSSOP-38-9	16	16
XMC1100-T038F0032	PG-TSSOP-38-9	32	16
XMC1100-T038F0064	PG-TSSOP-38-9	64	16
XMC1100-T038X0064	PG-TSSOP-38-9	64	16
XMC1100-Q024F0008	PG-VQFN-24-19	8	16
XMC1100-Q024F0016	PG-VQFN-24-19	16	16
XMC1100-Q024F0032	PG-VQFN-24-19	32	16
XMC1100-Q024F0064	PG-VQFN-24-19	64	16
XMC1100-Q040F0016	PG-VQFN-40-13	16	16
XMC1100-Q040F0032	PG-VQFN-40-13	32	16
XMC1100-Q040F0064	PG-VQFN-40-13	64	16

## 1.3 Device Type Features

The following table lists the available features per device type.

Table 2 Features of XMC1100 Device Types<sup>1)</sup>

Derivative	ADC channel	
XMC1100-T016	6	
XMC1100-T038	12	
XMC1100-Q024	8	
XMC1100-Q040	12	

<sup>1)</sup> Features that are not included in this table are available in all the derivatives.

Table 3 ADC Channels

Package	VADCO GO	VADC0 G1			
PG-TSSOP-16	CH0CH5	_			
A-blacentines A					

#### **Microcontroller Series for Industrial Applications**



#### 1 Summary of Features

Table 3 (continued) ADC Channels

Package	VADCO GO	VADC0 G1
PG-TSSOP-38	CH0CH7	CH1, CH5 CH7
PG-VQFN-24	CH0CH7	_
PG-VQFN-40	CH0CH7	CH1, CH5 CH7

## 1.4 Chip Identification Number

The Chip Identification Number allows software to identify the marking. It is a 8 words value with the most significant 7 words stored in Flash configuration sector 0 (CS0) at address location:  $1000~0F00_H~(MSB)$  -  $1000~0F1B_H~(LSB)$ . The least significant word and most significant word of the Chip Identification Number are the value of registers DBGROMID and IDCHIP, respectively.

Table 4 XMC1100 Chip Identification Number

Derivative	Value	Marking		
XMC1100-T016F0008	00011032 01CF00FF 00001F37 00000000 00000C00 00001000 00003000 201ED083 <sub>H</sub>			
XMC1100-T016F0016	00011032 01CF00FF 00001F37 00000000 00000C00 00001000 00005000 201ED083 <sub>H</sub>	AB		
XMC1100-T016F0032	00011032 01CF00FF 00001F37 00000000 00000C00 00001000 00009000 201ED083 <sub>H</sub>	AB		
XMC1100-T016F0064	00011032 01CF00FF 00001F37 00000000 00000C00 00001000 00011000 201ED083 <sub>H</sub>	AB		
XMC1100-T016X0016	00011033 01CF00FF 00001F37 00000000 00000C00 00001000 00005000 201ED083 <sub>H</sub>	AB		
XMC1100-T016X0032	00011033 01CF00FF 00001F37 00000000 00000C00 00001000 00009000 201ED083 <sub>H</sub>	AB		
XMC1100-T016X0064	00011033 01CF00FF 00001F37 00000000 00000C00 00001000 00011000 201ED083 <sub>H</sub>	AB		
XMC1100-T038F0016	00011012 01CF00FF 00001F37 00000000 00000C00 00001000 A			
XMC1100-T038F0032	100-T038F0032 00011012 01CF00FF 00001F37 00000000 00000C00 00001000 00009000 201ED083 <sub>H</sub>			
XMC1100-T038F0064	MC1100-T038F0064 00011012 01CF00FF 00001F37 00000000 00000C00 00001000 00011000 201ED083 <sub>H</sub>			
XMC1100-T038X0064	00011013 01CF00FF 00001F37 00000000 00000C00 00001000 00011000 201ED083 <sub>H</sub>	АВ		
XMC1100-Q024F0008	00011062 01CF00FF 00001F37 00000000 00000C00 00001000 00003000 201ED083 <sub>H</sub>	AB		
MC1100-Q024F0016 00011062 01CF00FF 00001F37 00000000 00000C00 00001000 00005000 201ED083 <sub>H</sub>				

## **Microcontroller Series for Industrial Applications**



## 1 Summary of Features

## Table 4 (continued) XMC1100 Chip Identification Number

Derivative	Value	Marking
XMC1100-Q024F0032	00011062 01CF00FF 00001F37 00000000 00000C00 00001000 00009000 201ED083 <sub>H</sub>	АВ
XMC1100-Q024F0064	00011062 01CF00FF 00001F37 00000000 00000C00 00001000 00011000 201ED083 <sub>H</sub>	АВ
XMC1100-Q040F0016	00011042 01CF00FF 00001F37 00000000 00000C00 00001000 00005000 201ED083 <sub>H</sub>	АВ
XMC1100-Q040F0032	00011042 01CF00FF 00001F37 00000000 00000C00 00001000 00009000 201ED083 <sub>H</sub>	АВ
XMC1100-Q040F0064	00011042 01CF00FF 00001F37 00000000 00000C00 00001000 00011000 201ED083 <sub>H</sub>	АВ



## 2 General Device Information

This section summarizes the logic symbols and package pin configurations with a detailed list of the functional I/O mapping.

## 2.1 Logic Symbols

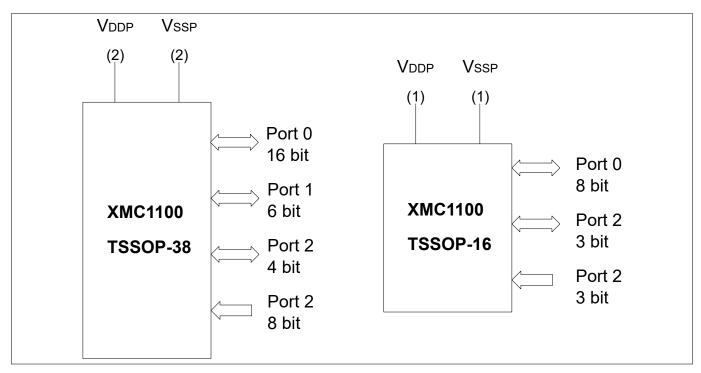


Figure 2 XMC1100 Logic Symbol for TSSOP-38 and TSSOP-16

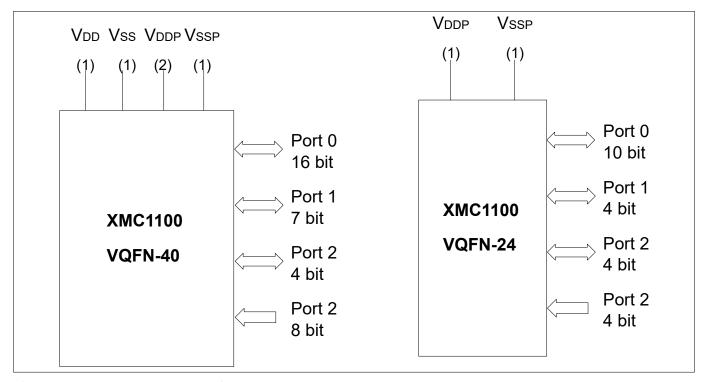


Figure 3 XMC1100 Logic Symbol for VQFN-24 and VQFN-40



## 2.2 Pin Configuration and Definition

The following figures summarize all pins, showing their locations on the different packages.

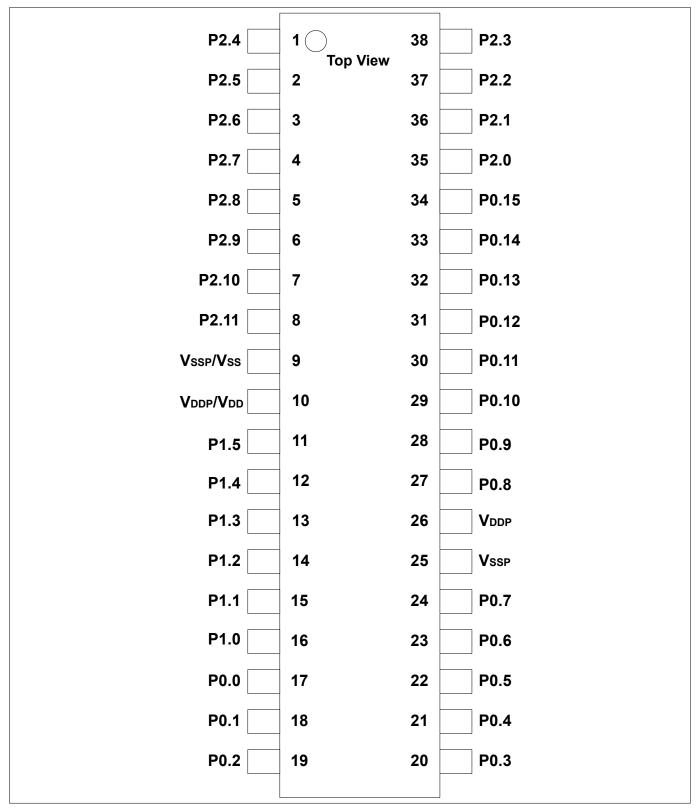


Figure 4 XMC1100 PG-TSSOP-38 Pin Configuration (top view)

V1.9



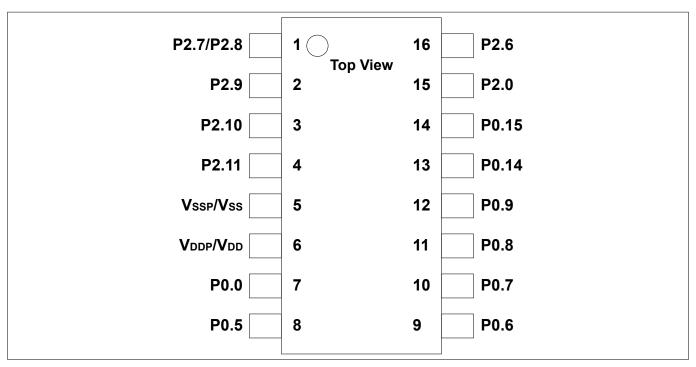


Figure 5 XMC1100 PG-TSSOP-16 Pin Configuration (top view)

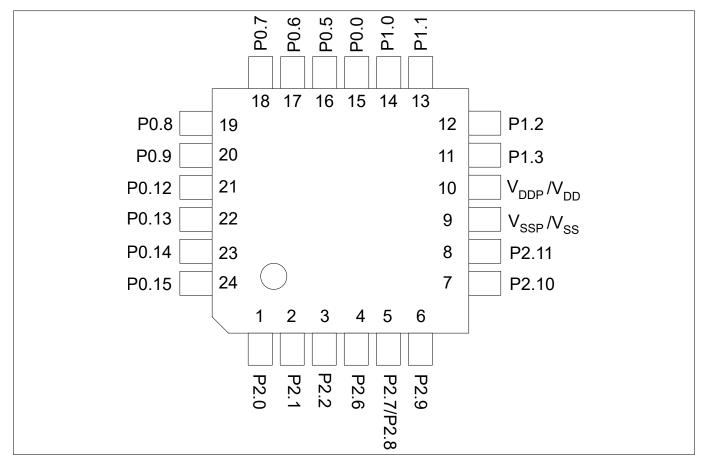


Figure 6 XMC1100 PG-VQFN-24 Pin Configuration (top view)

V1.9



#### 2 General Device Information

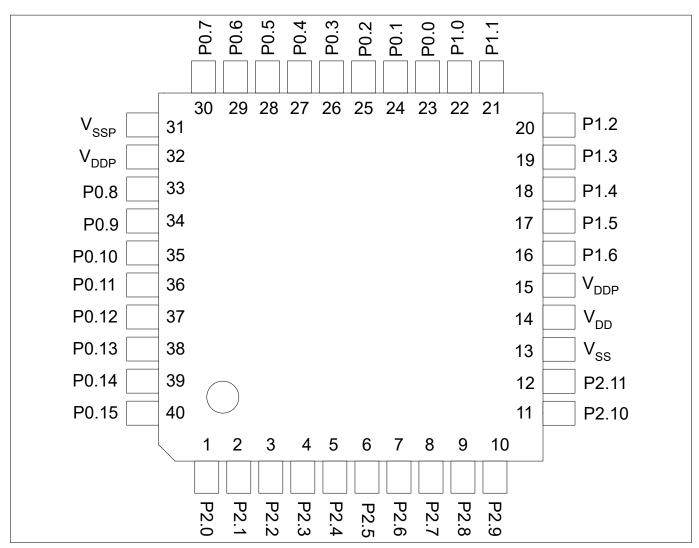


Figure 7 XMC1100 PG-VQFN-40 Pin Configuration (top view)

## 2.2.1 Package Pin Summary

The following general building block is used to describe each pin:

Table 5 Package Pin Mapping Description

Function	Package A	Package B	•••	Pad Type
Px.y	N	N		Pad Class

The table is sorted by the "Function" column, starting with the regular Port pins (Px.y), followed by the supply pins.

The following columns, titled with the supported package variants, lists the package pin number to which the respective function is mapped in that package.

The "Pad Type" indicates the employed pad type:

- STD INOUT (standard bi-directional pads)
- STD\_INOUT/AN (standard bi-directional pads with analog input)
- High Current (high current bi-directional pads)

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## 2 General Device Information

- STD\_IN/AN (standard input pads with analog input)
- Power (power supply)

Details about the pad properties are defined in the Electrical Parameters.

Table 6 Package Pin Mapping

Function	VQFN 40	TSSOP 38	VQFN 24	TSSOP 16	Pad Type	Notes
P0.0	23	17	15	7	STD_INOUT	
P0.1	24	18	_	_	STD_INOUT	
P0.2	25	19	_	_	STD_INOUT	
P0.3	26	20	_	_	STD_INOUT	
P0.4	27	21	_	_	STD_INOUT	
P0.5	28	22	16	8	STD_INOUT	
P0.6	29	23	17	9	STD_INOUT	
P0.7	30	24	18	10	STD_INOUT	
P0.8	33	27	19	11	STD_INOUT	
P0.9	34	28	20	12	STD_INOUT	
P0.10	35	29	_	_	STD_INOUT	
P0.11	36	30	_	_	STD_INOUT	
P0.12	37	31	21	_	STD_INOUT	
P0.13	38	32	22	_	STD_INOUT	
P0.14	39	33	23	13	STD_INOUT	
P0.15	40	34	24	14	STD_INOUT	
P1.0	22	16	14	_	High Current	
P1.1	21	15	13	_	High Current	
P1.2	20	14	12	_	High Current	
P1.3	19	13	11	_	High Current	
P1.4	18	12	_	_	High Current	
P1.5	17	11	_	_	High Current	
P1.6	16	_	_	_	STD_INOUT	
P2.0	1	35	1	15	STD_INOUT/AN	
P2.1	2	36	2	_	STD_INOUT/AN	
P2.2	3	37	3	_	STD_IN/AN	
P2.3	4	38	_	_	STD_IN/AN	
P2.4	5	1	_	_	STD_IN/AN	
P2.5	6	2	_	_	STD_IN/AN	
P2.6	7	3	4	16	STD_IN/AN	
P2.7	8	4	5	1	STD_IN/AN	

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## **2 General Device Information**

Table 6 (continued) Package Pin Mapping

Function	VQFN 40	TSSOP 38	VQFN 24	TSSOP 16	Pad Type	Notes
P2.8	9	5	5	1	STD_IN/AN	
P2.9	10	6	6	2	STD_IN/AN	
P2.10	11	7	7	3	STD_INOUT/AN	
P2.11	12	8	8	4	STD_INOUT/AN	
VSS	13	9	9	5	Power	Supply GND, ADC reference GND
VDD	14	10	10	6	Power	Supply VDD, ADC reference voltage/ORC reference voltage
VDDP	15	10	10	6	Power	When VDD is supplied, VDDP has to be supplied with the same voltage.
VSSP	31	25	_	_	Power	I/O port ground
VDDP	32	26	_	_	Power	I/O port supply
VSSP	Exp. Pad	-	Exp. Pad	-	Power	Exposed Die Pad  The exposed die pad is connected internally to VSSP. For proper operation, it is mandatory to connect the exposed pad to the board ground. For thermal aspects, please refer to the Package and Reliability chapter.

# 2.2.2 Port I/O Function Description

The following general building block is used to describe the I/O functions of each PORT pin:

Table 7 Port I/O Function Description

Function	Outputs		Inputs	
	ALT1	ALTn	Input	Input
P0.0		MODA.OUT	MODC.INA	
Pn.y	MODA.OUT		MODA.INA	MODC.INB



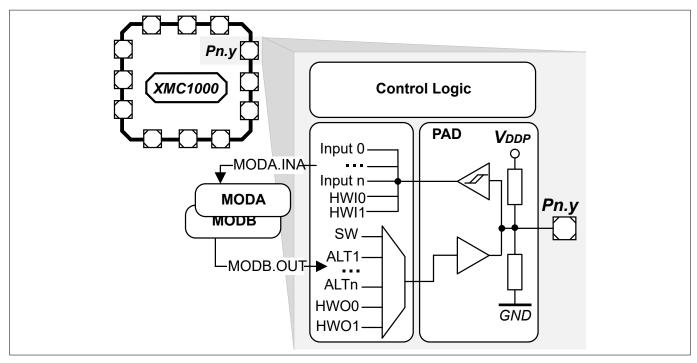


Figure 8 Simplified Port Structure

Pn.y is the port pin name, defining the control and data bits/registers associated with it. As GPIO, the port is under software control. Its input value is read via Pn\_IN.y, Pn\_OUT defines the output value.

Up to seven alternate output functions (ALT1/2/3/4/5/6/7) can be mapped to a single port pin, selected by Pn\_IOCR.PC. The output value is directly driven by the respective module, with the pin characteristics controlled by the port registers (within the limits of the connected pad).

The port pin input can be connected to multiple peripherals. Most peripherals have an input multiplexer to select between different possible input sources.

The input path is also active while the pin is configured as output. This allows to feedback an output to on-chip resources without wasting an additional external pin.

Please refer to Table 9 for the complete Port I/O function mapping.

## 2.2.3 Hardware Controlled I/O Function Description

The following general building block is used to describe the hardware I/O and pull control functions of each PORT pin:

Table 8 Hardware Controlled I/O Function Description

Function	Outputs	Inputs	Pull Control	
	HWO0	HWIO	HW0_PD	HW0_PU
P0.0	MODB.OUT	MODB.INA		
Pn.y			MODC.OUT	MODC.OUT

By Pn\_HWSEL, it is possible to select between different hardware "masters" (HWO0/HWI0, HWO1/HWI1). The selected peripheral can take control of the pin(s). Hardware control overrules settings in the respective port pin registers. Additional hardware signals HW0\_PD/HW1\_PD and HW0\_PU/HW1\_PU controlled by the peripherals can be used to control the pull devices of the pin.

Please refer to Table 10 for the complete hardware I/O and pull control function mapping.

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Function	Outputs							Inputs						
	ALT1	ALT2	ALT3	ALT4	ALTS	ALT6	ALT7	Input	Input	Input	Input	Input	Input	Input
P0.0	ERUO. PDOUT 0		ERU0. GOUT0	CCU40. OUT0		USICO_ CH0. SELO0	USICO_ CH1. SELOO	CCU40.I N0C				USICO_ CH0. DX2A	USICO_ CH1. DX2A	
P0.1	ERU0. PDOUT 1		ERU0. GOUT1	CCU40. OUT1			SCU. VDROP	CCU40.I N1C						
P0.2	ERUO. PDOUT 2		ERU0. GOUT2	CCU40. OUT2		VADC0. EMUX02		CCU40.I N2C						
P0.3	ERUO. PDOUT 3		ERU0. GOUT3	CCU40. OUT3		VADCO. EMUX01		CCU40.I N3C						
P0.4				CCU40. OUT1		VADCO. EMUXOO	WWDT. SERVIC E_OUT							
P0.5				CCU40. OUT0										
P0.6				CCU40. OUT0		USICO_ CH1.MC LKOUT	USICO_ CH1. DOUTO	CCU40.I N0B				USICO_ CH1. DX0C		
P0.7				CCU40. OUT1		USICO_ CH0. SCLKO UT	USICO_ CH1. DOUTO	CCU40.I N1B				USICO_ CH0. DX1C	USICO_ CH1. DX0D	USICO_ CH1. DX1C
P0.8				CCU40. OUT2		USICO_ CHO. SCLKO UT	USICO_ CH1. SCLKO UT	CCU40.I N2B				USICO_ CH0. DX1B	USICO_ CH1. DX1B	
(table continues	ıtinues)													

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Table 9	-	(continue	d) Port I	(continued) Port I/O Functio	SU									
Function	Outputs							Inputs						
	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	Input	Input	Input	Input	Input	Input	Input
P0.9				CCU40. OUT3		USICO_ CH0. SELO0	USICO_ CH1. SELOO	CCU40.I N3B				USICO_ CH0. DX2B	USICO_ CH1. DX2B	
P0.10						USICO_ CH0. SELO1	USICO_ CH1. SELO1					USICO_ CH0. DX2C	USICO_ CH1. DX2C	
P0.11				USICO_ CH0.MC LKOUT		USICO_ CH0. SELO2	USICO_ CH1. SELO2					USICO_ CH0. DX2D	USICO_ CH1. DX2D	
P0.12						USICO_ CH0. SELO3		CCU40.I NOA	CCU40.I N1A	CCU40.I N2A	CCU40.1 N3A	USICO_ CH0. DX2E		
P0.13	WWDT. SERVIC E_OUT					USICO_ CH0. SELO4						USICO_ CH0. DX2F		
P0.14						USICO_ CH0. DOUT0	USICO_ CHO. SCLKO UT					USICO_ CH0. DX0A	USICO_ CH0. DX1A	
P0.15						USICO_ CH0. DOUT0	USICO_ CH1.MC LKOUT					USICO_ CH0. DX0B		
P1.0		CCU40. OUT0					USICO_ CHO. DOUTO					USICO_ CH0. DX0C		
P1.1	VADCO. EMUXOO	CCU40. OUT1				USICO_ CH0. DOUT0	USICO_ CH1. SELOO					USICO_ CH0. DX0D	USICO_ CH0. DX1D	USICO_ CH1. DX2E
(table continues)	tinues)													

## **Microcontroller Series for Industrial Applications**

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Table 9	_	(continue	d) Port I/	(continued) Port I/O Functio	Su									
Function	Outputs							Inputs						
	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	Input	Input	Input	Input	Input	Input	Input
P1.2	VADCO. EMUX01	CCU40. OUT2					USICO_ CH1. DOUTO					USICO_ CH1. DX0B		
P1.3	VADCO. EMUX02	CCU40. OUT3				USICO_ CH1. SCLKO UT	USICO_ CH1. DOUTO					USICO_ CH1. DX0A	USICO_ CH1. DX1A	
P1.4	VADCO. EMUX10	USICO_ CH1. SCLKO UT				USICO_ CH0. SELO0	USICO_ CH1. SELO1					USICO_ CH0. DX5E	USICO_ CH1. DX5E	
P1.5	VADCO. EMUX11	USICO_ CH0. DOUT0				USICO_ CH0. SELO1	USICO_ CH1. SELO2					USICO_ CH1. DX5F		
P1.6	VADCO. EMUX12	USICO_ CH1.DO UT0		USICO_ CH0.SC LKOUT		USICO_ CH0.SE LO2	USICO_ CH1.SE LO3			USICO_ CH0.DX 5F				
P2.0	ERUO. PDOUT 3	CCU40. OUT0	ERU0. GOUT3			USICO_ CH0. DOUT0	USICO_ CHO. SCLKO UT		VADC0. G0CH5		ERUO.0 B0	USICO_ CH0. DX0E	USICO_ UCHO. CHO.	USICO_ CH1. DX2F
P2.1	ERUO. PDOUT 2	CCU40. OUT1	ERU0. GOUT2			USICO_ CH0. DOUT0	USICO_ CH1. SCLKO UT		VADC0. G0CH6		ERU0.1 B0	USICO_ CH0. DX0F	USICO_ UCH1.	USICO_ CH1. DX4A
P2.2									VADC0. G0CH7		ERU0.0 B1	USICO_ CH0. DX3A	USICO_ UCHO. CHO. DX4A	USICO_ CH1. DX5A
(table continues)	tinues)											-	_	

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Table 9		(continued) Port I/O Functions	d) Port I/	O Functio	Su									
Function	Outputs							Inputs						
	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	Input	Input	Input	Input	Input	Input	Input
P2.3									VADCO. G1CH5		ERU0.1 B1	USICO_ CH0. DX5B	USICO_ CH1. DX3C	USICO_ CH1. DX4C
P2.4									VADCO. G1CH6		ERU0.0 A1	USICO_ CH0. DX3B	USICO_ CH0. DX4B	USICO_ CH1. DX5B
P2.5									VADCO. G1CH7		ERUO.1 A1	USICO_ CH0. DX5D	USICO_ CH1. DX3E	USICO_ CH1. DX4E
P2.6									VADC0. G0CH0		ERU0.2 A1	USICO_ CH0. DX3E	USICO_ CH0. DX4E	USICO_ CH1. DX5D
P2.7									VADC0. G1CH1		ERU0.3 A1	USICO_ CH0. DX5C	USICO_ CH1. DX3D	USICO_ CH1. DX4D
P2.8									VADC0. G0CH1		ERU0.3 B1	USICO_ CH0. DX3D	USICO_ CH0. DX4D	USICO_ CH1. DX5C
P2.9									VADC0. G0CH2		ERU0.3 B0	USICO_ CH0. DX5A	USICO_ CH1. DX3B	USICO_ CH1. DX4B
P2.10	ERU0. PDOUT 1	CCU40. OUT2	ERU0. GOUT1				USICO_ CH1. DOUTO		VADC0. G0CH3		ERU0.2 B0	USICO_ CH0. DX3C	USICO_ CH0. DX4C	USICO_ CH1. DX0F
P2.11	ERUO. PDOUT 0	CCU40. OUT3	ERUO. GOUTO			USICO_ CH1. SCLKO UT	USICO_ CH1. DOUTO		VADC0. G0CH4		ERU0.2 B1	USICO_ CH1. DX0E	USICO_ CH1. DX1E	

# **Microcontroller Series for Industrial Applications**

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Table 10	Hardware	Hardware Controlled I/O Functions	/O Functions					
Function	Outputs		Inputs		Pull Control			
	НМОО	HW01	HWIO	HWI1	HW0_PD	HW0_PU	HW1_PD	HW1_PU
P0.0								
P0.1								
P0.2								
P0.3								
P0.4								
P0.5								
P0.6								
P0.7								
P0.8								
P0.9								
P0.10								
P0.11								
P0.12								
P0.13								
P0.14								
P0.15								
P1.0		USICO_CHO . DOUTO		USICO_CHO . HWINO				
P1.1		USICO_CHO . DOUT1		USICO_CHO .HWIN1				
P1.2		USICO_CHO . DOUT2		USICO_CH0 . HWIN2				
(table continues)	§)							

# **Microcontroller Series for Industrial Applications**



Table 10	(continue	(continued) Hardware (	Controlled I	Controlled I/O Functions				
Function	Outputs		Inputs		Pull Control			
	НМОО	HW01	HWIO	HWI1	HW0_PD	HW0_PU	HW1_PD	HW1_PU
P1.3		USICO_CHO . DOUT3		USICO_CHO . HWIN3				
P1.4								
P1.5								
P1.6								
P2.0								
P2.1								
P2.2							<u>CCU40.0UT3</u>	CCU40.0UT3
P2.3								
P2.4								
P2.5								
P2.6							<u>CCU40.0UT3</u>	CCU40.0UT3
P2.7							<u>CCU40.0UT3</u>	CCU40.0UT3
P2.8							<u>CCU40.0UT2</u>	CCU40.0UT2
P2.9							<u>CCU40.0UT2</u>	CCU40.0UT2
P2.10								
P2.11								

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#### 3 Electrical Parameters

## 3 Electrical Parameters

This section provides the electrical parameters which are implementation-specific for the XMC1100.

#### 3.1 General Parameters

## 3.1.1 Parameter Interpretation

The parameters listed in this section represent partly the characteristics of the XMC1100 and partly its requirements on the system. To aid interpreting the parameters easily when evaluating them for a design, they are indicated by the abbreviations in the "Symbol" column:

#### cc

Such parameters indicate **C**ontroller **C**haracteristics, which are distinctive feature of the XMC1100 and must be regarded for a system design.

#### SR

Such parameters indicate **S**ystem **R**equirements, which must be provided by the application system in which the XMC1100 is designed in.

## 3.1.2 Absolute Maximum Ratings

Stresses above the values listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

Table 11 Absolute Maximum Rating Parameters

Parameter	Symbol	Value	5		Unit	Note/Test
		Min.	Тур.	Max.		Condition
Junction temperature	T <sub>J</sub> SR	-40	-	115	°C	-
Storage temperature	T <sub>ST</sub> SR	-40	-	125	°C	_
Voltage on power supply pin with respect to $V_{\rm SSP}$	V <sub>DDP</sub> SR	-0.3	_	6	V	-
Voltage on digital pins with respect to $V_{\rm SSP}^{1/2}$	V <sub>IN</sub> SR	-0.5	_	V <sub>DDP</sub> + 0.5 or max. 6	V	whichever is lower
Voltage on P2 pins with respect to $V_{\rm SSP}^{2)}$	V <sub>INP2</sub> SR	-0.3	_	V <sub>DDP</sub> + 0.3	V	-
Voltage on analog input pins with respect to $V_{\rm SSP}$	V <sub>AIN</sub> V <sub>AREF</sub> SR	-0.5	_	V <sub>DDP</sub> + 0.5 or max. 6	V	whichever is lower
Input current on any pin during overload condition	I <sub>IN</sub> SR	-10	_	10	mA	-
Absolute maximum sum of all input currents during overload condition	$\Sigma I_{IN} SR$	-50	_	+50	mA	-

<sup>1)</sup> Excluding port pins P2.[1,2,6,7,8,9,11].

<sup>2)</sup> Applicable to port pins P2.[1,2,6,7,8,9,11].

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#### 3 Electrical Parameters

## 3.1.3 Pin Reliability in Overload

When receiving signals from higher voltage devices, low-voltage devices experience overload currents and voltages that go beyond their own IO power supplies specification.

Table 12 defines overload conditions that will not cause any negative reliability impact if all the following conditions are met:

- full operation life-time is not exceeded
- Operating Conditions are met for
  - pad supply levels (V<sub>DDP</sub>)
  - temperature

If a pin current is outside of the Operating Conditions but within the overload conditions, then the parameters of this pin as stated in the Operating Conditions can no longer be guaranteed. Operation is still possible in most cases but with relaxed parameters.

**Note**: An overload condition on one or more pins does not require a reset.

**Note**: A series resistor at the pin to limit the current to the maximum permitted overload current is sufficient to handle failure situations like short to battery.

Table 12 Overload Parameters

Parameter	Symbol	Values	i		Unit	Note/Test
		Min.	Тур.	Мах.		Condition
Input current on any port pin during overload condition	I <sub>OV</sub> SR	-5	_	5	mA	
Absolute sum of all input circuit currents during overload condition	I <sub>OVS</sub> SR	-	-	25	mA	

Figure 9 shows the path of the input currents during overload via the ESD protection structures. The diodes against  $V_{\rm DDP}$  and ground are a simplified representation of these ESD protection structures.

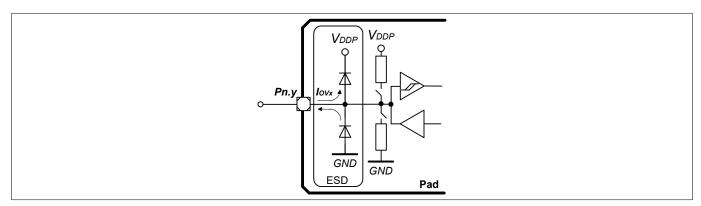


Figure 9 Input Overload Current via ESD structures

#### **Microcontroller Series for Industrial Applications**



#### **3 Electrical Parameters**

Table 13 and Table 14 list input voltages that can be reached under overload conditions. Note that the absolute maximum input voltages as defined in the Absolute Maximum Ratings must not be exceeded during overload.

Table 13 PN-Junction Characteristics for positive Overload

Pad Type	I <sub>OV</sub> = 5 mA
Standard, High-current,	$V_{\rm IN} = V_{\rm DDP} + 0.5  \rm V$
AN/DIG_IN	$V_{\text{AIN}} = V_{\text{DDP}} + 0.5 \text{ V}$
	$V_{\text{AREF}} = V_{\text{DDP}} + 0.5 \text{ V}$
P2.[1,2,6:9,11]	$V_{\rm INP2} = V_{\rm DDP} + 0.3  \rm V$

Table 14 PN-Junction Characteristics for negative Overload

Pad Type	I <sub>OV</sub> = 5 mA
Standard, High-current,	$V_{IN} = V_{SS} - 0.5 \text{ V}$
AN/DIG_IN	$V_{AIN} = V_{SS} - 0.5 \text{ V}$ $V_{AREF} = V_{SS} - 0.5 \text{ V}$
	$V_{AREF} = V_{SS} - 0.5 V$
P2.[1,2,6:9,11]	$V_{\text{INP2}} = V_{\text{SS}} - 0.3 \text{ V}$

## 3.1.4 Operating Conditions

The following operating conditions must not be exceeded in order to ensure correct operation and reliability of the XMC1100. All parameters specified in the following tables refer to these operating conditions, unless noted otherwise.

Table 15 Operating Conditions Parameters

Parameter	Symbol	Values			Unit	<b>Note/Test Condition</b>
		Min.	Тур.	Max.		
Ambient Temperature	T <sub>A</sub> SR	-40	_	85	°C	Temp. Range F
		-40	_	105	°C	Temp. Range X
Digital supply voltage <sup>1)</sup>	V <sub>DDP</sub> SR	1.8	_	5.5	V	
MCLK Frequency	$f_{MCLK}$ CC	_	_	33.2	MHz	CPU clock
PCLK Frequency	$f_{PCLK}CC$	_	_	66.4	MHz	Peripherals clock
Short circuit current of digital outputs	I <sub>SC</sub> SR	-5	-	5	mA	
Absolute sum of short circuit currents of the device	$\Sigma I_{SC_D} SR$	-	-	25	mA	

<sup>1)</sup> See also the Supply Monitoring thresholds, Chapter 3.3.2.

## **Microcontroller Series for Industrial Applications**

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#### **3 Electrical Parameters**

## 3.2 DC Parameters

## 3.2.1 Input/Output Characteristics

Table 16 provides the characteristics of the input/output pins of the XMC1100.

**Note**: These parameters are not subject to production test, but verified by design and/or characterization.

**Note**: Unless otherwise stated, input DC and AC characteristics, including peripheral timings, assume that

the input pads operate with the standard hysteresis.

Table 16 Input/Output Characteristics (Operating Conditions apply)

Parameter	Symbol	Limit Valu	ies	Unit	Note/Test Condition	
		Min.	Max.			
Output low voltage on port	V <sub>OLP</sub> CC	_	1.0	٧	I <sub>OL</sub> = 11 mA (5 V)	
pins (with standard pads)					$I_{OL} = 7 \text{ mA } (3.3 \text{ V})$	
		-	0.4	V	$I_{OL} = 5 \text{ mA } (5 \text{ V})$	
					$I_{OL} = 3.5 \text{ mA } (3.3 \text{ V})$	
Output low voltage on high	V <sub>OLP1</sub> CC	_	1.0	V	I <sub>OL</sub> = 50 mA (5 V)	
current pads					$I_{OL} = 25 \text{ mA } (3.3 \text{ V})$	
		_	0.32	V	I <sub>OL</sub> = 10 mA (5 V)	
		-	0.4	V	$I_{OL} = 5 \text{ mA } (3.3 \text{ V})$	
Output high voltage on port	V <sub>OHP</sub> CC	V <sub>DDP</sub> - 1.0	_	V	I <sub>OH</sub> = -10 mA (5 V)	
pins (with standard pads)					$I_{OH} = -7 \text{ mA } (3.3 \text{ V})$	
		V <sub>DDP</sub> - 0.4	_	V	I <sub>OH</sub> = -4.5 mA (5 V)	
					$I_{OH} = -2.5 \text{ mA } (3.3 \text{ V})$	
Output high voltage on high current pads	V <sub>OHP1</sub> CC	<i>V</i> <sub>DDP</sub> - 0.32	_	V	$I_{OH} = -6 \text{ mA } (5 \text{ V})$	
		V <sub>DDP</sub> - 1.0	_	V	I <sub>OH</sub> = -8 mA (3.3 V)	
		V <sub>DDP</sub> - 0.4	-	٧	I <sub>OH</sub> = -4 mA (3.3 V)	
Input low voltage on port pins	V <sub>ILPS</sub> SR	-	0.19×	V	CMOS Mode	
(Standard Hysteresis)			$V_{DDP}$		(5 V, 3.3 V & 2.2 V)	
Input high voltage on port	V <sub>IHPS</sub> SR	$0.7 \times V_{\text{DDP}}$	-	V	CMOS Mode	
pins (Standard Hysteresis)					(5 V, 3.3 V & 2.2 V)	
Input low voltage on port pins	V <sub>ILPL</sub> SR	_	0.08 ×	V	CMOS Mode	
(Large Hysteresis)			$V_{DDP}$		(5 V, 3.3 V & 2.2 V) <sup>10)</sup>	
Input high voltage on port	V <sub>IHPL</sub> SR	0.85 ×	_	V	CMOS Mode	
pins (Large Hysteresis)		$V_{DDP}$			(5 V, 3.3 V & 2.2 V) <sup>10)</sup>	

## **Microcontroller Series for Industrial Applications**



#### **3 Electrical Parameters**

Table 16 (continued) Input/Output Characteristics (Operating Conditions apply)

Parameter	Symbol	Limit Valu	ies	Unit	Note/Test Condition	
		Min.	Max.			
Rise time on High Current	t <sub>HCPR</sub> CC	_	9	ns	50 pF @ 5 V <sup>2)</sup>	
Pad <sup>1)</sup>		_	12	ns	50 pF @ 3.3 V <sup>3)</sup>	
		_	25	ns	50 pF @ 1.8 V <sup>4)</sup>	
Fall time on High Current	t <sub>HCPF</sub> CC	_	9	ns	50 pF @ 5 V <sup>2)</sup>	
Pad <sup>1)</sup>		_	12	ns	50 pF @ 3.3 V <sup>3)</sup>	
		_	25	ns	50 pF @ 1.8 V <sup>4)</sup>	
Rise time on Standard Pad <sup>1)</sup>	t <sub>R</sub> CC	_	12	ns	50 pF @ 5 V <sup>5)</sup>	
		_	15	ns	50 pF @ 3.3 V <sup>6)</sup>	
		_	31	ns	50 pF @ 1.8 V <sup>7)</sup>	
Fall time on Standard Pad <sup>1)</sup>	t <sub>F</sub> CC	_	12	ns	50 pF @ 5 V <sup>5)</sup>	
		_	15	ns	50 pF @ 3.3 V <sup>6)</sup>	
		_	31	ns	50 pF @ 1.8 V <sup>7)</sup>	
Input Hysteresis <sup>8)</sup>	HYS CC	0.08 × V <sub>DDP</sub>	_	V	CMOS Mode (5 V), Standard Hysteresis	
		0.03 × V <sub>DDP</sub>	_	V	CMOS Mode (3.3 V), Standard Hysteresis	
		0.02 × V <sub>DDP</sub>	_	V	CMOS Mode (2.2 V), Standard Hysteresis	
		0.5 × <i>V</i> <sub>DDP</sub>	0.75 × V <sub>DDP</sub>	V	CMOS Mode(5 V), Large Hysteresis	
		0.4 × V <sub>DDP</sub>	0.75 × V <sub>DDP</sub>	V	CMOS Mode(3.3 V), Large Hysteresis	
		0.2 × V <sub>DDP</sub>		V	CMOS Mode(2.2 V), Large Hysteresis	
Pin capacitance (digital inputs/outputs)	C <sub>IO</sub> CC	-	10	pF		
Pull-up resistor on port pins	R <sub>PUP</sub> CC	20	50	kohm	$V_{\rm IN} = V_{\rm SSP}$	
Pull-down resistor on port pins	R <sub>PDP</sub> CC	20	50	kohm	$V_{\rm IN} = V_{\rm DDP}$	
Input leakage current <sup>9)</sup>	I <sub>OZP</sub> CC	-1	1	μΑ	$0 < V_{\rm IN} < V_{\rm DDP},$ $T_{\rm A} \le 105^{\circ}{\rm C}$	
Voltage on any pin during V <sub>DDP</sub> power off	V <sub>PO</sub> SR	-	0.3	V	10)	
Maximum current per pin (excluding P1, V <sub>DDP</sub> and V <sub>SS</sub> )	I <sub>MP</sub> SR	-10	11	mA	-	



#### **3 Electrical Parameters**

Table 16 (continued) Input/Output Characteristics (Operating Conditions apply)

Parameter	Symbol	Limit V	alues	Unit	<b>Note/Test Condition</b>	
		Min.	Max.			
Maximum current per high current pins	I <sub>MP1A</sub> SR	-10	50	mA	-	
Maximum current into $V_{\rm DDP}$ (TSSOP28/16, VQFN24)	I <sub>MVDD1</sub> SR	-	130	mA	10)	
Maximum current into $V_{\rm DDP}$ (TSSOP38, VQFN40)	I <sub>MVDD2</sub> SR	_	260	mA	10)	
Maximum current out of $V_{SS}$ (TSSOP28/16, VQFN24)	I <sub>MVSS1</sub> SR	-	130	mA	10)	
Maximum current out of V <sub>SS</sub> (TSSOP38, VQFN40)	I <sub>MVSS2</sub> SR	-	260	mA	10)	

- 1) Rise/Fall time parameters are taken with 10% 90% of supply.
- 2) Additional rise/fall time valid for  $C_L = 50 \text{ pF} C_L = 100 \text{ pF} @ 0.150 \text{ ns/pF}$  at 5 V supply voltage.
- 3) Additional rise/fall time valid for  $C_L$  = 50 pF  $C_L$  = 100 pF @ 0.205 ns/pF at 3.3 V supply voltage.
- 4) Additional rise/fall time valid for  $C_L = 50 \text{ pF} C_L = 100 \text{ pF} @ 0.445 \text{ ns/pF} \text{ at } 1.8 \text{ V supply voltage.}$
- 5) Additional rise/fall time valid for  $C_L$  = 50 pF  $C_L$  = 100 pF @ 0.225 ns/pF at 5 V supply voltage.
- 6) Additional rise/fall time valid for  $C_L = 50 \text{ pF} C_L = 100 \text{ pF}$  @ 0.288 ns/pF at 3.3 V supply voltage.
- 7) Additional rise/fall time valid for  $C_L = 50 \text{ pF} C_L = 100 \text{ pF} @ 0.588 \text{ ns/pF} \text{ at } 1.8 \text{ V supply voltage.}$
- 8) Hysteresis is implemented to avoid meta stable states and switching due to internal ground bounce. It cannot be guaranteed that it suppresses switching due to external system noise.
- 9) An additional error current  $(I_{INJ})$  will flow if an overload current flows through an adjacent pin.
- 10) However, for applications with strict low power-down current requirements, it is mandatory that no active voltage source is supplied at any GPIO pin when V<sub>DDP</sub> is powered off.

## 3.2.2 Analog to Digital Converters (ADC)

Table 17 shows the Analog to Digital Converter (ADC) characteristics.

**Note**: These parameters are not subject to production test, but verified by design and/or characterization.

Table 17 ADC Characteristics (Operating Conditions apply)<sup>1)</sup>

Parameter	Symbol	Values			Unit	<b>Note/Test Condition</b>
		Min.	Тур.	Max.		
Supply voltage range (internal reference)	V <sub>DD_int</sub> SR	2.0	-	3.0	V	$\begin{array}{c} {\rm SHSCFG.AREF=11_B} \\ {\rm CALCTR.CALGNSTC=0C_H} \end{array}$
		3.0	_	5.5	V	SHSCFG.AREF = 10 <sub>B</sub>
Supply voltage range (external reference)	V <sub>DD_ext</sub> SR	3.0	-	5.5	V	SHSCFG.AREF = 00 <sub>B</sub>
Analog input voltage range	V <sub>AIN</sub> SR	V <sub>SSP</sub> - 0.05	-	V <sub>DDP</sub> + 0.05	V	
Auxiliary analog reference ground	V <sub>REFGND</sub> SR	V <sub>SSP</sub> - 0.05	-	1.0	V	G0CH0

## **Microcontroller Series for Industrial Applications**



## **3 Electrical Parameters**

(continued) ADC Characteristics (Operating Conditions apply) $^{1)}$ Table 17

Parameter	Symbol	Values	-		Unit	<b>Note/Test Condition</b>
		Min.	Тур.	Max.		
Internal reference voltage (full scale value)	V <sub>REFINT</sub> CC	5	5		V	
Switched capacitance of an analog input	C <sub>AINS</sub> CC	-	1.2	2	pF	GNCTRxz.GAINy = 00 <sub>B</sub> (unity gain)
		-	1.2	2	pF	GNCTRxz.GAINy = 01 <sub>B</sub> (gain g1)
		-	4.5	6	pF	GNCTRxz.GAINy = 10 <sub>B</sub> (gain g2)
		-	4.5	6	pF	GNCTRxz.GAINy = 11 <sub>B</sub> (gain g3)
Total capacitance of an analog input	C <sub>AINT</sub> CC	-	-	10	pF	
Total capacitance of the reference input	C <sub>AREFT</sub> CC	-	-	10	pF	
Gain settings	G <sub>IN</sub> CC	1	1			GNCTRxz.GAINy = 00 <sub>B</sub> (unity gain)
		3			_	GNCTRxz.GAINy = 01 <sub>B</sub> (gain g1)
		6	6			GNCTRxz.GAINy = 10 <sub>B</sub> (gain g2)
		12	12			GNCTRxz.GAINy = 11 <sub>B</sub> (gain g3)
Sample Time	t <sub>sample</sub> CC	4	-	_	$1/f_{ADC}$	V <sub>DD</sub> = 5.0 V
		4	-	_	$1/f_{ADC}$	V <sub>DD</sub> = 3.3 V
		30	_	_	$1/f_{ADC}$	V <sub>DD</sub> = 2.0 V
Sigma delta loop hold time	t <sub>SD_hold</sub> CC	20	_	_	μs	Residual charge stored in an active sigma delta loop remains available
Conversion time in fast compare mode	t <sub>CF</sub> CC	9			1/f <sub>ADC</sub>	2)
Conversion time in 12-bit mode	t <sub>C12</sub> CC	20	20			2)
Maximum sample rate in 12- bit mode <sup>3)</sup>	f <sub>C12</sub> CC	-	_	f <sub>ADC</sub> / 43.5	-	1 sample pending
		-	-	f <sub>ADC</sub> / 63.5	-	2 samples pending
Conversion time in 10-bit mode	t <sub>C10</sub> CC	18	<u>'</u>		1/f <sub>ADC</sub>	2)

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#### **3 Electrical Parameters**

(continued) ADC Characteristics (Operating Conditions apply)<sup>1)</sup> Table 17

Parameter	Symbol	Values	;		Unit	Note/Test Condition
		Min.	Тур.	Max.		
Maximum sample rate in 10- bit mode <sup>3)</sup>	f <sub>C10</sub> CC	-	-	f <sub>ADC</sub> / 41.5	-	1 sample pending
		-	-	f <sub>ADC</sub> / 59.5	-	2 samples pending
Conversion time in 8-bit mode	t <sub>C8</sub> CC	16			1/f <sub>ADC</sub>	2)
Maximum sample rate in 8- bit mode <sup>3)</sup>	f <sub>C8</sub> CC	-	-	f <sub>ADC</sub> / 38.5	-	1 sample pending
		-	-	f <sub>ADC</sub> / 54.5	_	2 samples pending
RMS noise <sup>4)</sup>	EN <sub>RMS</sub> CC	-	1.5	-	LSB12	DC input, V <sub>DD</sub> = 5.0 V, V <sub>AIN</sub> = 2.5 V, 25°C
DNL error	EA <sub>DNL</sub> CC	-	±2.0	_	LSB12	
INL error	EA <sub>INL</sub> CC	_	±4.0	_	LSB12	
Gain error with external reference	EA <sub>GAIN</sub> CC	-	±0.5	-	%	SHSCFG.AREF = 00 <sub>B</sub> (calibrated)
Gain error with internal reference <sup>5)</sup>	EA <sub>GAIN</sub> CC	-	±3.6	-	%	SHSCFG.AREF = $1X_B$ (calibrated),
						-40°C - 105°C
		-	±2.0	-	%	SHSCFG.AREF = 1X <sub>B</sub> (calibrated),
000						0°C - 85°C
Offset error	EA <sub>OFF</sub> CC	_	±8.0	-	mV	Calibrated,
						$V_{\rm DD} = 5.0 \text{ V}$

<sup>1)</sup> The parameters are defined for ADC clock frequency  $f_{\rm SH}$  = 32 MHz.

<sup>2)</sup> 3) 4) No pending samples assumed, excluding sampling time and calibration.

Includes synchronization and calibration (average of gain and offset calibration).

This parameter can also be defined as an SNR value:  $SNR[dB] = 20 \times log(A_{MAXeff}/N_{RMS})$ .

With  $A_{MAXeff} = 2N/2$ ,  $SNR[dB] = 20 \times log (2048/N_{RMS}) [N = 12]$ .

 $N_{\rm RMS}$  = 1.5 LSB12, therefore, equals SNR = 20 × log (2048/1.5) = 62.7 dB.

<sup>5)</sup> Includes error from the reference voltage.



#### **3 Electrical Parameters**

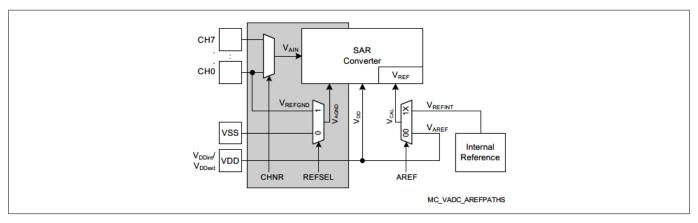


Figure 10 ADC Voltage Supply

## **3.2.3** Temperature Sensor Characteristics

**Note**: These parameters are not subject to production test, but verified by design and/or characterization.

**Table 18** Temperature Sensor Characteristics

Parameter	Symbol	Values	Values			Note/Test Condition
		Min.	Тур.	Max.		
Measurement time	t <sub>M</sub> CC	_	_	10	ms	
Temperature sensor range	T <sub>SR</sub> SR	-40	_	115	°C	
Sensor Accuracy <sup>1)</sup>	T <sub>TSAL</sub> CC	-6	_	6	°C	<i>T</i> <sub>J</sub> > 20°C
		-10	_	10	°C	0°C ≤ <i>T</i> <sub>J</sub> ≤ 20°C
		-18	_	18	°C	-25°C ≤ T <sub>J</sub> < 0°C
		-31	_	31	°C	-40°C ≤ T <sub>J</sub> < -25°C
Start-up time after enabling	$t_{TSSTE}SR$	_	_	15	μs	

<sup>1)</sup> The temperature sensor accuracy is independent of the supply voltage.

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#### **3 Electrical Parameters**

## 3.2.4 Power Supply Current

The total power supply current defined below consists of a leakage and a switching component. Application relevant values are typically lower than those given in the following tables, and depend on the customer's system operating conditions (e.g. thermal connection or used application configurations).

**Note**: These parameters are not subject to production test, but verified by design and/or characterization.

Table 19 Power Supply Parameters;  $V_{DDP} = 5 \text{ V}$ 

Parameter	Symbol	Value	s		Unit	Note/Test Condition
		Min.	Typ. <sup>1)</sup>	Max.		
Active mode current	I <sub>DDPAE</sub> CC	_	8.4	11.0	mA	32/64
Peripherals enabled		_	7.3	_	mA	24/48
f <sub>MCLK</sub> /f <sub>PCLK</sub> in MHz <sup>2)</sup>		_	6.1	_	mA	16/32
		_	5.1	_	mA	8/16
		_	3.7	_	mA	1/1
Active mode current	I <sub>DDPAD</sub> CC	_	4.7	_	mA	32/64
Peripherals disabled		_	4.1	_	mA	24/48
f <sub>MCLK</sub> /f <sub>PCLK</sub> in MHz <sup>3)</sup>		_	3.3	_	mA	16/32
		_	2.6	_	mA	8/16
		_	1.5	_	mA	1/1
Active mode current	I <sub>DDPAR</sub> CC	_	6.3	_	mA	32/64
Code execution from RAM		_	5.4	_	mA	24/48
Flash is powered down		_	4.6	_	mA	16/32
$f_{\text{MCLK}}/f_{\text{PCLK}}$ in MHz		_	3.8	_	mA	8/16
		_	3.0	_	mA	1/1
Sleep mode current	I <sub>DDPSE</sub> CC	_	5.9	_	mA	32/64
Peripherals clock enabled			5.4	_	mA	24/48
f <sub>MCLK</sub> /f <sub>PCLK</sub> in MHz <sup>4)</sup>			4.8	_	mA	16/32
			4.3	_	mA	8/16
			3.7	_	mA	1/1
Sleep mode current	I <sub>DDPSD</sub> CC	_	1.8	_	mA	32/64
Peripherals clock disabled			1.7	_	mA	24/48
Flash active			1.6	_	mA	16/32
$f_{\text{MCLK}}/f_{\text{PCLK}}$ in MHz <sup>5)</sup>			1.5	_	mA	8/16
			1.4	_	mA	1/1
			1			1

#### **3 Electrical Parameters**

Table 19 (continued) Power Supply Parameters;  $V_{DDP} = 5 \text{ V}$ 

Parameter	Symbol	Value	s		Unit	Note/Test Condition
		Min.	Typ. 1)	Max.		
Sleep mode current	I <sub>DDPSR</sub> CC	-	1.2	-	mA	32/64
Peripherals clock disabled			1.1	_	mA	24/48
Flash powered down $f_{\rm MCLK}/f_{\rm PCLK}$ in MHz <sup>6)</sup>			1.0	_	mA	16/32
IVITIZ			0.8	-	mA	8/16
			0.7	_	mA	1/1
Deep Sleep mode current <sup>7)</sup>	I <sub>DDPDS</sub> CC	_	0.24	-	mA	
Wake-up time from Sleep to Active mode <sup>8)</sup>	t <sub>SSA</sub> CC	_	6	_	cycles	
Wake-up time from Deep Sleep to Active mode <sup>9)</sup>	t <sub>DSA</sub> CC	-	280	-	μsec	

- 1) The typical values are measured at  $T_A = +25$ °C and  $V_{DDP} = 5$  V.
- CPU and all peripherals clock enabled, Flash is in active mode. 2)
- 3) CPU enabled, all peripherals clock disabled, Flash is in active mode.
- 4) CPU in sleep, all peripherals clock enabled and Flash is in active mode.
- 5) CPU in sleep, Flash is in active mode.
- CPU in sleep, Flash is powered down and code executed from RAM after wake-up.
- 6) 7) CPU in sleep, peripherals clock disabled, Flash is powered down and code executed from RAM after wake-up.
- 8) CPU in sleep, Flash is in active mode during sleep mode.
- CPU in sleep, Flash is in powered down mode during deep sleep mode.

Figure 11 shows typical graphs for active mode supply current for  $V_{DDP} = 5 \text{ V}$ ,  $V_{DDP} = 3.3 \text{ V}$ ,  $V_{DDP} = 1.8 \text{ V}$  across different clock frequencies.

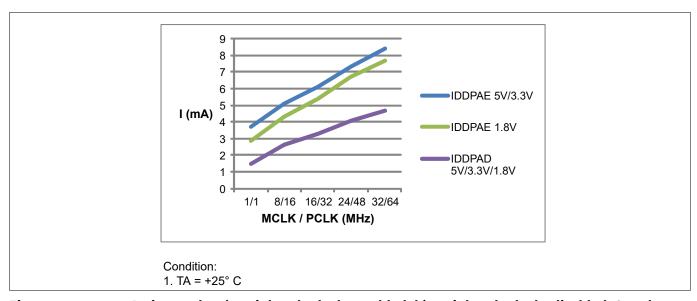


Figure 11 Active mode, a) peripherals clocks enabled, b) peripherals clocks disabled: Supply current I<sub>DDPA</sub> over supply voltage V<sub>DDP</sub> for different clock frequencies



#### 3 Electrical Parameters

Figure 12 shows typical graphs for sleep mode current for  $V_{DDP} = 5 \text{ V}$ ,  $V_{DDP} = 3.3 \text{ V}$ ,  $V_{DDP} = 1.8 \text{ V}$  across different clock frequencies.

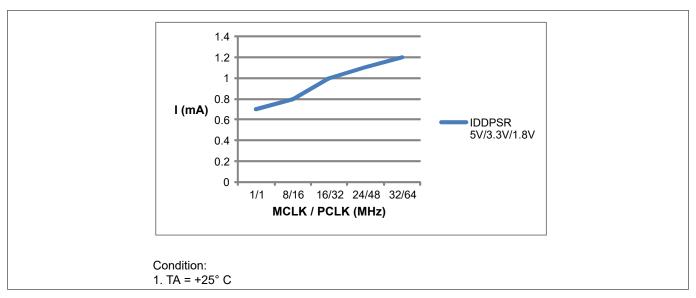


Figure 12 Sleep mode, peripherals clocks disabled, Flash powered down: Supply current  $I_{DDPSR}$  over supply voltage  $V_{DDP}$  for different clock frequencies

Table 20 provides the active current consumption of some modules operating at 5 V power supply at 25°C. The typical values shown are used as a reference guide on the current consumption when these modules are enabled.

Table 20 Typical Active Current Consumption

<b>Active Current</b>	Symbol	<b>Limit Values</b>	Unit	Note/Test Condition		
Consumption		Тур.				
Baseload current	I <sub>CPUDDC</sub>	5.04	mA	Modules including Core, SCU, PORT, memories, ANATOP <sup>1)</sup>		
VADC and SHS	I <sub>ADCDDC</sub>	3.4	mA	Set CGATCLR0.VADC to 1 <sup>2)</sup>		
USIC0	I <sub>USICODDC</sub>	0.87	mA	Set CGATCLR0.USIC0 to 1 <sup>3)</sup>		
CCU40	I <sub>CCU40DDC</sub>	0.94	mA	Set CGATCLR0.CCU40 to 1 <sup>4)</sup>		
WDT	I <sub>WDTDDC</sub>	0.03	mA	Set CGATCLR0.WDT to 1 <sup>5)</sup>		
RTC	I <sub>RTCDDC</sub>	0.01	mA	Set CGATCLR0.RTC to 1 <sup>6)</sup>		

<sup>1)</sup> Baseload current is measured with device running in user mode, MCLK=PCLK=32 MHz, with an endless loop in the flash memory. The clock to the modules stated in CGATSTAT0 are gated.

<sup>2)</sup> Active current is measured with: module enabled, MCLK=32 MHz, running in auto-scan conversion mode.

<sup>3)</sup> Active current is measured with: module enabled, alternating messages sent to PC at 57.6 kbaud every 200 ms.

<sup>4)</sup> Active current is measured with: module enabled, MCLK=PCLK=32 MHz, 1 CCU4 slice for PWM switching from 1500 Hz and 1000 Hz at regular intervals, 1 CCU4 slice in capture mode for reading period and duty cycle.

<sup>5)</sup> Active current is measured with: module enabled, MCLK=32 MHz, time-out mode; WLB = 0, WUB = 0x00008000; WDT serviced every 1 s.

<sup>6)</sup> Active current is measured with: module enabled, MCLK=32 MHz, Periodic interrupt enabled.

## **Microcontroller Series for Industrial Applications**



#### **3 Electrical Parameters**

## 3.2.5 Flash Memory Parameters

**Note**: These parameters are not subject to production test, but verified by design and/or characterization.

Table 21 Flash Memory Parameters

Parameter	Symbol	Value	s		Unit	Note/Test Condition
		Min.	Тур.	Max.		
Erase Time per page/sector	t <sub>ERASE</sub> CC	6.8	7.1	7.6	ms	
Program time per block	t <sub>PSER</sub> CC	102	152	204	μs	
Wake-Up time	t <sub>WU</sub> CC	_	32.2	_	μs	
Read time per word	t <sub>a</sub> CC	_	50	_	ns	
Data Retention Time	t <sub>RET</sub> CC	10	_	_	years	Max. 100 erase/program cycles
Flash Wait States <sup>1)</sup>	N <sub>WSFLASH</sub> CC	0	0	0		$f_{MCLK}$ = 8 MHz
		0	1	1		$f_{MCLK}$ = 16 MHz
		1	1.3	2		$f_{MCLK}$ = 32 MHz
Fixed Flash Wait States configured in bit	N <sub>FWSFLASH</sub> SR	0	0	1		NVM_CONFIG1.FIXWS = $1_B$ , $f_{MCLK} \le 16 \text{ MHz}$
NVM_NVMCONF.WS		1	1	1		NVM_CONFIG1.FIXWS = $1_B$ , $16 \text{ MHz} < f_{\text{MCLK}} \le 32 \text{ MHz}$
Erase Cycles	N <sub>ECYC</sub> CC	-		5*10 <sup>4</sup>	cycles	Sum of page and sector erase cycles
Total Erase Cycles	N <sub>TECYC</sub> CC	_	_	2*10 <sup>6</sup>	cycles	

<sup>1)</sup> Flash wait states are automatically inserted by the Flash module during memory read when needed. Typical values are calculated from the execution of the Dhrystone benchmark program.



#### 3 Electrical Parameters

## 3.3 AC Parameters

## 3.3.1 Testing Waveforms

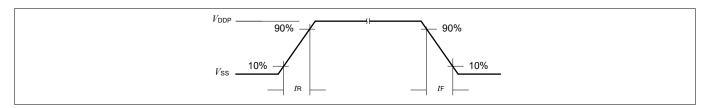


Figure 13 Rise/Fall Time Parameters

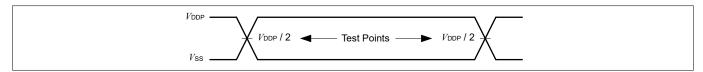


Figure 14 Testing Waveform, Output Delay

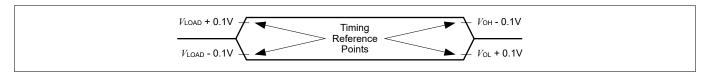


Figure 15 Testing Waveform, Output High Impedance

## 3.3.2 Power-Up and Supply Monitoring Characteristics

Table 22 provides the characteristics of the supply monitoring in XMC1100.

The guard band between the lowest valid operating voltage and the brownout reset threshold provides a margin for noise immunity and hysteresis. The electrical parameters may be violated while  $V_{\rm DDP}$  is outside its operating range.

The brownout detection triggers a reset within the defined range. The prewarning detection can be used to trigger an early warning and issue corrective and/or fail-safe actions in case of a critical supply voltage drop.

**Note**: These parameters are not subject to production test, but verified by design and/or characterization.

## **Microcontroller Series for Industrial Applications**



#### **3 Electrical Parameters**

Table 22 Power-Up and Supply Monitoring Parameters (Operating Conditions apply)<sup>1)</sup>

Parameter	Symbol	Values			Unit	Note/Test Condition	
		Min.	Тур.	Max.			
V <sub>DDP</sub> ramp-up time	$t_{RAMPUP}SR$	V <sub>DDP</sub> / S <sub>VDDPrise</sub>	_	10 <sup>7</sup>	μs		
V <sub>DDP</sub> slew rate	S <sub>VDDPOP</sub> SR	0	_	0.1	V/µs	Slope during normal operation	
	S <sub>VDDP10</sub> SR	0	_	10	V/μs	Slope during fast transient within +/-10% of V <sub>DDP</sub>	
	S <sub>VDDPrise</sub> SR	0	_	10	V/μs	Slope during power-on or restart after brownout event	
	S <sub>VDDPfall</sub> <sup>2)</sup> SR	0	_	0.25	V/µs	Slope during supply falling out of the +/-10% limits <sup>3)</sup>	
V <sub>DDP</sub> prewarning voltage	V <sub>DDPPW</sub> CC	2.1	2.25	2.4	V	ANAVDEL.VDEL_SELECT = 00 <sub>B</sub>	
		2.85	3	3.15	V	ANAVDEL.VDEL_SELECT = 01 <sub>B</sub>	
		4.2	4.4	4.6	V	ANAVDEL.VDEL_SELECT = 10 <sub>B</sub>	
$V_{\text{DDP}}$ brownout reset voltage	V <sub>DDPBO</sub> CC	1.55	1.62	1.75	V	calibrated, before user code starts running	
V <sub>DDP</sub> voltage to ensure defined pad states	V <sub>DDPPA</sub> CC	-	1.0	-	V		
Start-up time from power-on reset	t <sub>SSW</sub> SR	-	320	_	μs	Time to the first user code instruction in all start-up modes <sup>4)</sup>	
BMI program time	t <sub>BMI</sub> SR	-	8.25	_	ms	Time taken from a user- triggered system reset after BMI installation is requested	

<sup>1)</sup> Not all parameters are 100% tested, but are verified by design/characterization.

<sup>2)</sup> A capacitor of at least 100 nF has to be added between  $V_{\text{DDP}}$  and  $V_{\text{SSP}}$  to fulfill the requirement as stated for this parameter.

<sup>3)</sup> Valid for a 100 nF buffer capacitor connected to supply pin where current from capacitor is forwarded only to the chip. A larger capacitor value has to be chosen if the power source sink a current.

<sup>4)</sup> This values does not include the ramp-up time. During start-up firmware execution, MCLK is running at 32 MHz and the clocks to peripheral as specified in register CGATSTATO are gated.

#### **Microcontroller Series for Industrial Applications**



#### **3 Electrical Parameters**

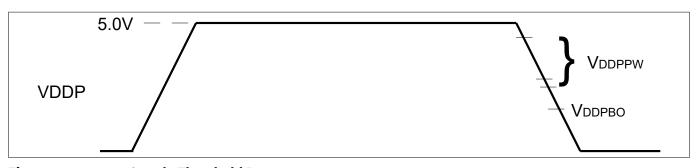


Figure 16 Supply Threshold Parameters

### 3.3.3 On-Chip Oscillator Characteristics

**Note**: These parameters are not subject to production test, but verified by design and/or characterization.

Table 23 provides the characteristics of the 64 MHz clock output from the digital controlled oscillator, DCO1 in XMC1100.

Table 23 64 MHz DCO1 Characteristics (Operating Conditions apply)

Parameter	Symbol	Limit Values			Unit	Note/Test Condition
	Min.	Тур.	Max.			
Nominal frequency	$f_{NOM} CC$	-	64	-	MHz	under nominal conditions <sup>1)</sup> after trimming
Accuracy <sup>2)</sup>	$\Delta f_{LT} CC$	-1.7	_	3.4	%	with respect to $f_{NOM}(typ)$ , over temperature (0°C to 85°C)
		-3.9	_	4.0	%	with respect to $f_{NOM}(typ)$ , over temperature (-40°C to 105°C)

<sup>1)</sup> The deviation is relative to the factory trimmed frequency at nominal  $V_{\rm DDC}$  and  $T_{\rm A}$  = + 25°C.

Figure 17 shows the typical curves for the accuracy of DCO1, with and without calibration based on temperature sensor, respectively.

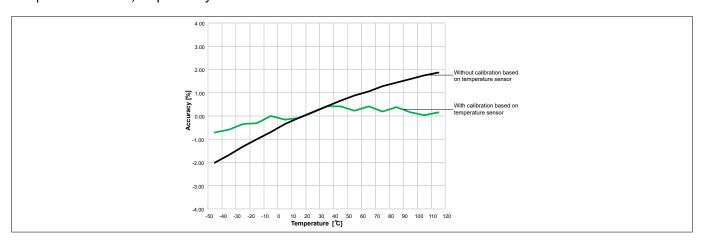


Figure 17 Typical DCO1 accuracy over temperature

Table 24 provides the characteristics of the 32 kHz clock output from digital controlled oscillators, DCO2 in XMC1100.

<sup>2)</sup> The accuracy of the DCO1 oscillator can be further improved through alternative methods, refer to XMC1000 Oscillator Handling Application Note.

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#### **3 Electrical Parameters**

Table 24 32 kHz DCO2 Characteristics (Operating Conditions apply)

Parameter Symbol	Symbol	Limit Values			Unit	Note/Test Condition	
		Min.	Тур.	Max.			
Nominal frequency	$f_{NOM}CC$	INOM		under nominal conditions <sup>1)</sup> after rimming			
Accuracy	$\Delta f_{LT}$ CC	-1.7	-	3.4	%	with respect to $f_{NOM}(typ)$ , over temperature (0°C to 85°C)	
		-3.9	-	4.0	%	with respect to $f_{NOM}(typ)$ , over temperature (-40°C to 105°C)	

<sup>1)</sup> The deviation is relative to the factory trimmed frequency at nominal  $V_{\rm DDC}$  and  $T_{\rm A}$  = + 25°C.

## 3.3.4 Serial Wire Debug Port (SW-DP) Timing

The following parameters are applicable for communication through the SW-DP interface.

**Note**: These parameters are not subject to production test, but verified by design and/or characterization.

Table 25 SWD Interface Timing Parameters (Operating Conditions apply)

Parameter	Symbol	Values			Unit	Note/Test Condition
		Min.	Тур.	Max.		
SWDCLK high time	$t_1$ SR	50	-	500000	ns	-
SWDCLK low time	t <sub>2</sub> SR	50	-	500000	ns	-
SWDIO input setup to SWDCLK rising edge	t <sub>3</sub> SR	10	_	_	ns	-
SWDIO input hold after SWDCLK rising edge	t <sub>4</sub> SR	10	_	_	ns	-
SWDIO output valid time after	t <sub>5</sub> CC	_	-	68	ns	C <sub>L</sub> = 50 pF
SWDCLK rising edge		_	_	62	ns	C <sub>L</sub> = 30 pF
SWDIO output hold time from SWDCLK rising edge	t <sub>6</sub> CC	4	_	-	ns	

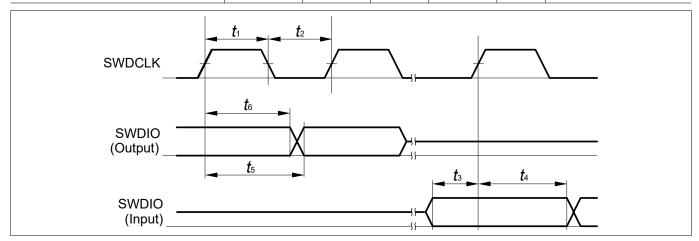


Figure 18 SWD Timing

V1.9

#### **Microcontroller Series for Industrial Applications**

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#### 3 Electrical Parameters

### 3.3.5 SPD Timing Requirements

The optimum SPD decision time between  $0_B$  and  $1_B$  is 0.75  $\mu$ s. With this value the system has maximum robustness against frequency deviations of the sampling clock on tool and on device side. However it is not always possible to exactly match this value with the given constraints for the sample clock. For instance for a oversampling rate of 4, the sample clock will be 8 MHz and in this case the closest possible effective decision time is 5.5 clock cycles (0.69  $\mu$ s).

Table 26 Optimum Number of Sample Clocks for SPD

Sample Freq.	Sampling Factor	Sample Clocks 0 <sub>B</sub>	Sample Clocks 1 <sub>B</sub>	Effective Decision Time <sup>1)</sup>	Remark
8 MHz	4	1 to 5	6 to 12	0.69 μs	The other closest option (0.81 µs) for the effective decision time is less robust.

Nominal sample frequency period multiplied with 0.5 + (max. number of 0<sub>B</sub> sample clocks).

For a balanced distribution of the timing robustness of SPD between tool and device, the timing requirements for the tool are:

- Frequency deviation of the sample clock is +/- 5%
- Effective decision time is between 0.69 μs and 0.75 μs (calculated with nominal sample frequency)

## 3.3.6 Peripheral Timings

**Note**: These parameters are not subject to production test, but verified by design and/or characterization.

## 3.3.6.1 Synchronous Serial Interface (USIC SSC) Timing

The following parameters are applicable for a USIC channel operated in SSC mode.

**Note**: Operating Conditions apply.

Table 27 USIC SSC Master Mode Timing

Parameter	Symbol	Values			Unit	Note/Test Condition
		Min.	Тур.	Max.		
SCLKOUT master clock period	t <sub>CLK</sub> CC	62.5	_	_	ns	
Slave select output SELO active to first SCLKOUT transmit edge	t <sub>1</sub> CC	80	_	_	ns	
Slave select output SELO inactive after last SCLKOUT receive edge	t <sub>2</sub> CC	0	_	_	ns	
Data output DOUT[3:0] valid time	t <sub>3</sub> CC	-10	_	10	ns	
Receive data input DX0/DX[5:3] setup time to SCLKOUT receive edge	t <sub>4</sub> SR	80	-	-	ns	
Data input DX0/DX[5:3] hold time from SCLKOUT receive edge	t₅ SR	0	-	-	ns	

## **Microcontroller Series for Industrial Applications**



Table 28 USIC SSC Slave Mode Timing

Parameter	Symbol	Values			Unit	Note/Test Condition
		Min.	Тур.	Max.		
DX1 slave clock period	t <sub>CLK</sub> SR	125	_	_	ns	
Select input DX2 setup to first clock input DX1 transmit edge <sup>1)</sup>	t <sub>10</sub> SR	10	-	_	ns	
Select input DX2 hold after last clock input DX1 receive edge <sup>1)</sup>	<i>t</i> <sub>11</sub> SR	10	-	_	ns	
Receive data input DX0/DX[5:3] setup time to shift clock receive edge <sup>1)</sup>	t <sub>12</sub> SR	10	-	_	ns	
Data input DX0/DX[5:3] hold time from clock input DX1 receive edge <sup>1)</sup>	t <sub>13</sub> SR	10	-	_	ns	
Data output DOUT[3:0] valid time	t <sub>14</sub> CC	_	_	80	ns	

<sup>1)</sup> These input timings are valid for asynchronous input signal handling of slave select input, shift clock input, and receive data input (bits DXnCR.DSEN = 0).

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#### **3 Electrical Parameters**

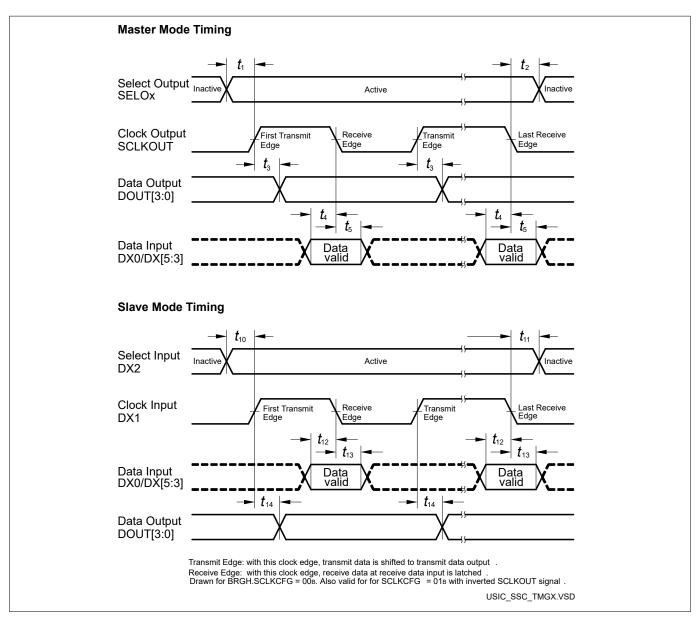


Figure 19 USIC - SSC Master/Slave Mode Timing

**Note**: This timing diagram shows a standard configuration, for which the slave select signal is low-active, and the serial clock signal is not shifted and not inverted.

## 3.3.6.2 Inter-IC (IIC) Interface Timing

The following parameters are applicable for a USIC channel operated in IIC mode.

**Note**: Operating Conditions apply.

Table 29 USIC IIC Standard Mode Timing<sup>1)</sup>

Parameter	Symbol	Values	Values		Unit	Note/Test
		Min.	Тур.	Max.		Condition
Fall time of both SDA and SCL	$t_1$ CC/SR	_	_	300	ns	

(table continues...)

#### **Microcontroller Series for Industrial Applications**



Table 29 (continued) USIC IIC Standard Mode Timing<sup>1)</sup>

Parameter	Symbol	Values	1		Unit	Note/Test
		Min.	Тур.	Max.		Condition
Rise time of both SDA and SCL	t <sub>2</sub> CC/SR	_	_	1000	ns	
Data hold time	t <sub>3</sub> CC/SR	0	_	_	μs	
Data set-up time	t <sub>4</sub> CC/SR	250	_	_	ns	
LOW period of SCL clock	t <sub>5</sub> CC/SR	4.7	_	-	μs	
HIGH period of SCL clock	t <sub>6</sub> CC/SR	4.0	_	-	μs	
Hold time for (repeated) START condition	t <sub>7</sub> CC/SR	4.0	_	_	μs	
Set-up time for repeated START condition	t <sub>8</sub> CC/SR	4.7	_	_	μs	
Set-up time for STOP condition	t <sub>9</sub> CC/SR	4.0	_	_	μs	
Bus free time between a STOP and START condition	t <sub>10</sub> CC/SR	4.7	_	-	μs	
Capacitive load for each bus line	C <sub>b</sub> SR	_	_	400	pF	

<sup>1)</sup> Due to the wired-AND configuration of an IIC bus system, the port drivers of the SCL and SDA signal lines need to operate in open-drain mode. The high level on these lines must be held by an external pull-up device, approximately 10 kOhm for operation at 100 kbit/s, approximately 2 kOhm for operation at 400 kbit/s.

Table 30 USIC IIC Fast Mode Timing<sup>1)</sup>

Parameter	Symbol	Values		Unit	Note/Test	
		Min.	Тур.	Max.		Condition
Fall time of both SDA and SCL	$t_1$ CC/SR	$20 + 0.1 * C_b^{2)}$	_	300	ns	
Rise time of both SDA and SCL	$t_2$ CC/SR	20 + 0.1*C <sub>b</sub>	_	300	ns	
Data hold time	t <sub>3</sub> CC/SR	0	_	_	μs	
Data set-up time	t <sub>4</sub> CC/SR	100	_	_	ns	
LOW period of SCL clock	t <sub>5</sub> CC/SR	1.3	_	_	μs	
HIGH period of SCL clock	$t_6$ CC/SR	0.6	_	_	μs	
Hold time for (repeated) START condition	t <sub>7</sub> CC/SR	0.6	_	_	μs	
Set-up time for repeated START condition	t <sub>8</sub> CC/SR	0.6	_	_	μs	
Set-up time for STOP condition	t <sub>9</sub> CC/SR	0.6	_	_	μs	
Bus free time between a STOP and START condition	$t_{10}$ CC/SR	1.3	-	_	μs	
Capacitive load for each bus line	C <sub>b</sub> SR	-	_	400	pF	

<sup>1)</sup> Due to the wired-AND configuration of an IIC bus system, the port drivers of the SCL and SDA signal lines need to operate in open-drain mode. The high level on these lines must be held by an external pull-up device, approximately 10 kOhm for operation at 100 kbit/s, approximately 2 kOhm for operation at 400 kbit/s.

<sup>2)</sup>  $C_b$  refers to the total capacitance of one bus line in pF.



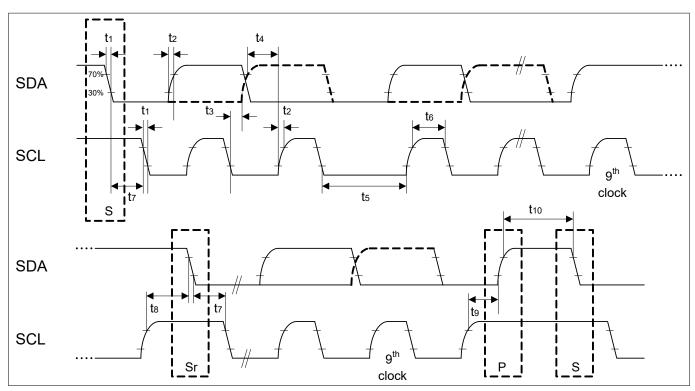


Figure 20 USIC IIC Stand and Fast Mode Timing

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#### **3 Electrical Parameters**

## 3.3.6.3 Inter-IC Sound (IIS) Interface Timing

The following parameters are applicable for a USIC channel operated in IIS mode.

**Note**: Operating Conditions apply.

Table 31 USIC IIS Master Transmitter Timing

Parameter	Symbol	Values		Unit	Note/Test	
		Min.	Тур.	Max.		Condition
Clock period	t <sub>1</sub> CC	2/f <sub>MCLK</sub>	_	_	ns	<i>V</i> <sub>DDP</sub> ≥ 3 V
		4/f <sub>MCLK</sub>	-	_	ns	<i>V</i> <sub>DDP</sub> < 3 V
Clock HIGH	t <sub>2</sub> CC	0.35 × t <sub>1min</sub>	_	_	ns	
Clock Low	t <sub>3</sub> CC	0.35 × t <sub>1min</sub>	_	_	ns	
Hold time	t <sub>4</sub> CC	0	_	_	ns	
Clock rise time	t <sub>5</sub> CC	-	_	0.15 ×	ns	
				$t_{1min}$		

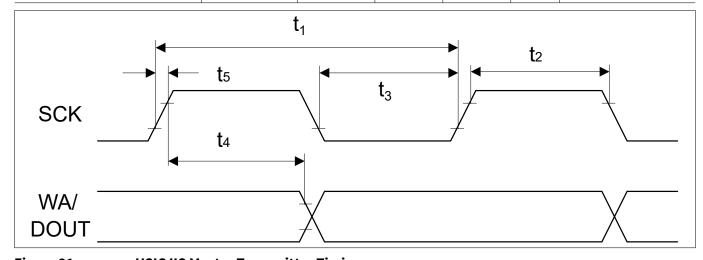


Figure 21 USIC IIS Master Transmitter Timing



Table 32 USIC IIS Slave Receiver Timing

Parameter	Symbol	Symbol Values				
		Min.	Тур.	Max.		Condition
Clock period	t <sub>6</sub> SR	4/f <sub>MCLK</sub>	_	_	ns	
Clock HIGH	t <sub>7</sub> SR	0.35 × t <sub>6min</sub>	_	_	ns	
Clock Low	t <sub>8</sub> SR	0.35 × t <sub>6min</sub>	_	_	ns	
Set-up time	t <sub>9</sub> SR	0.2 × t <sub>6min</sub>	_	_	ns	
Hold time	t <sub>10</sub> SR	10	_	-	ns	

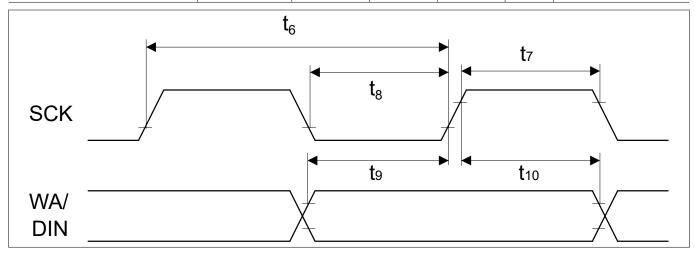


Figure 22 USIC IIS Slave Receiver Timing

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#### 4 Package and Reliability

## 4 Package and Reliability

The XMC1100 is a member of the XMC1000 Family of microcontrollers. It is also compatible to a certain extent with members of similar families or subfamilies.

Each package is optimized for the device it houses. Therefore, there may be slight differences between packages of the same pin-count but for different device types. In particular, the size of the exposed die pad may vary.

If different device types are considered or planned for an application, it must be ensured that the board layout fits all packages under consideration.

### 4.1 Package Parameters

Table 33 provides the thermal characteristics of the packages used in XMC1100.

Table 33 Thermal Characteristics of the Packages

Parameter	Symbol	Symbol Limit Val		Unit	Package Types	
		Min.	Max.			
Exposed Die Pad Dimensions	Ex × Ey CC	_	2.7 × 2.7	mm	PG-VQFN-24-19	
		_	3.7 × 3.7	mm	PG-VQFN-40-13	
Thermal resistance Junction-	$R_{\Theta JA}CC$	_	104.6	K/W	PG-TSSOP-16-8 <sup>1)</sup>	
Ambient		_	70.3	K/W	PG-TSSOP-38-9 <sup>1)</sup>	
		_	46.0	K/W	PG-VQFN-24-19 <sup>1)</sup>	
		_	38.4	K/W	PG-VQFN-40-13 <sup>1)</sup>	

<sup>1)</sup> Device mounted on a 4-layer JEDEC board (JESD 51-5); exposed pad soldered.

Note:

For electrical reasons, it is required to connect the exposed pad to the board ground V<sub>SSP</sub>, independent of EMC and thermal requirements.

#### 4.1.1 Thermal Considerations

When operating the XMC1100 in a system, the total heat generated in the chip must be dissipated to the ambient environment to prevent overheating and the resulting thermal damage.

The maximum heat that can be dissipated depends on the package and its integration into the target board. The "Thermal resistance  $R_{\Theta JA}$ " quantifies these parameters. The power dissipation must be limited so that the average junction temperature does not exceed 115°C.

The difference between junction temperature and ambient temperature is determined by

$$\Delta T = (P_{\text{INT}} + P_{\text{IOSTAT}} + P_{\text{IODYN}}) \times R_{\Theta \text{JA}}$$

The internal power consumption is defined as

 $P_{\text{INT}} = V_{\text{DDP}} \times I_{\text{DDP}}$  (switching current and leakage current).

The static external power consumption caused by the output drivers is defined as

$$P_{\text{IOSTAT}} = \Sigma((V_{\text{DDP}} - V_{\text{OH}}) \times I_{\text{OH}}) + \Sigma(V_{\text{OL}} \times I_{\text{OL}})$$

The dynamic external power consumption caused by the output drivers ( $P_{\text{IODYN}}$ ) depends on the capacitive load connected to the respective pins and their switching frequencies.

If the total power dissipation for a given system configuration exceeds the defined limit, countermeasures must be taken to ensure proper system operation:

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#### 4 Package and Reliability

- Reduce  $V_{DDP}$ , if possible in the system
- Reduce the system frequency
- Reduce the number of output pins
- Reduce the load on active output drivers

## 4.2 Package Outlines

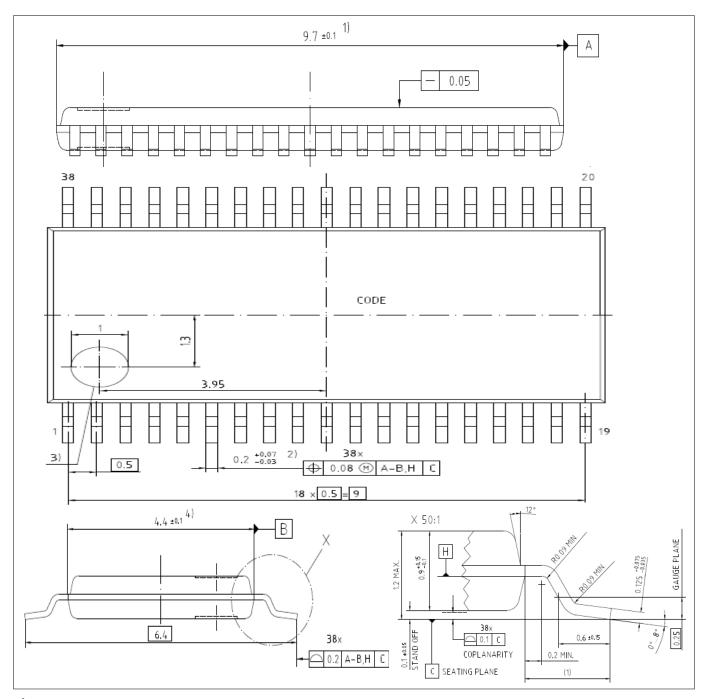


Figure 23 PG-TSSOP-38-9



## 4 Package and Reliability

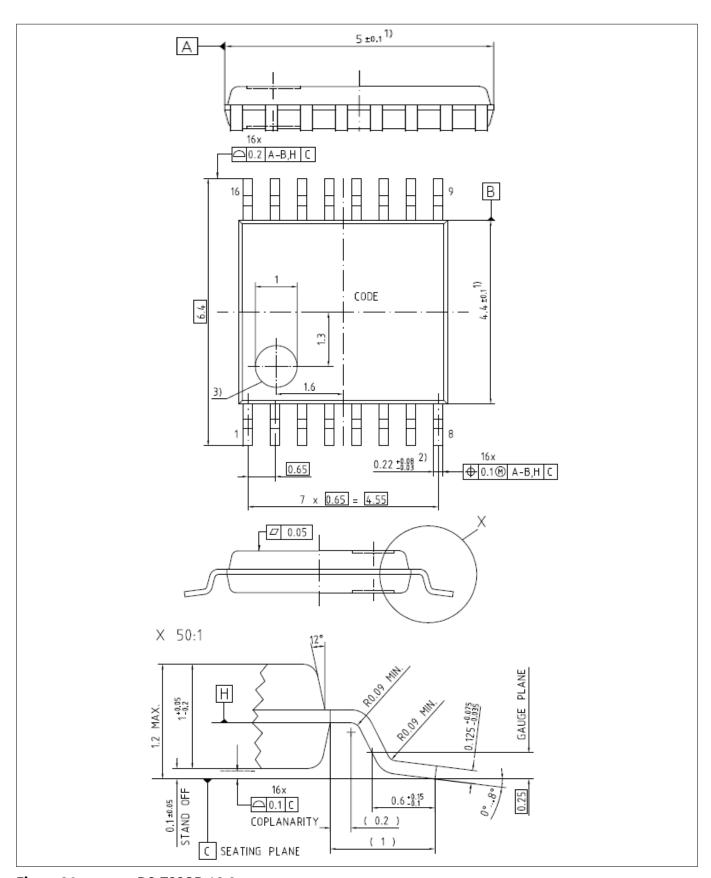


Figure 24 PG-TSSOP-16-8



## 4 Package and Reliability

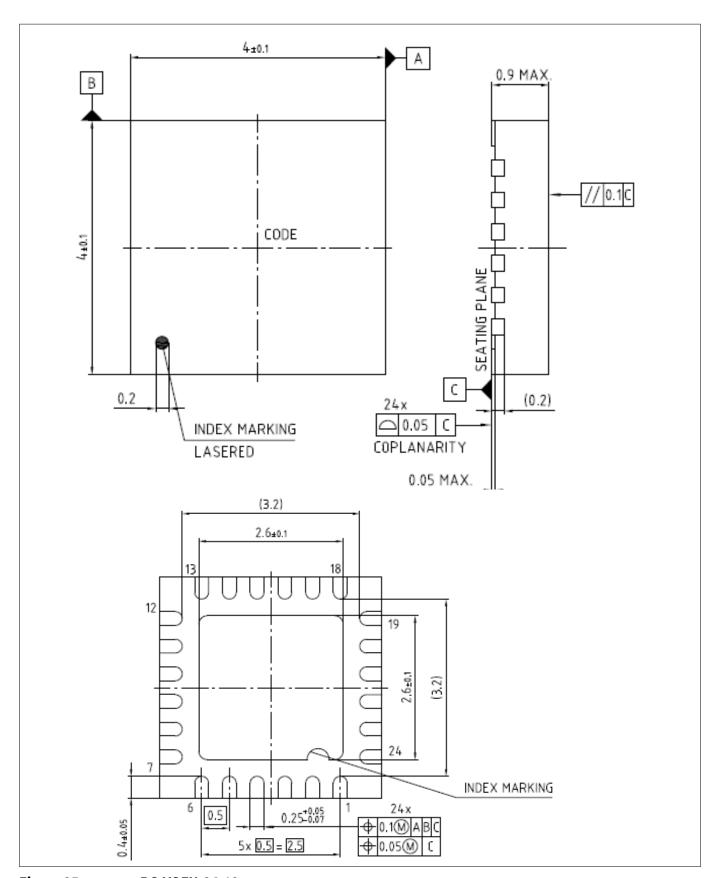


Figure 25 PG-VQFN-24-19

### 4 Package and Reliability

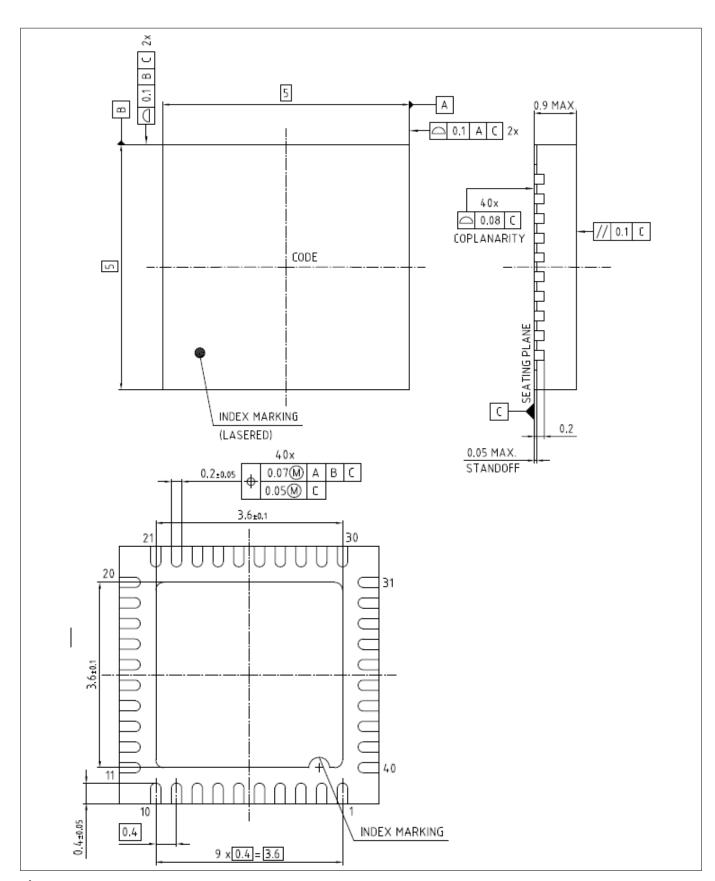


Figure 26 PG-VQFN-40-13

All dimensions in mm.

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## **5 Quality Declaration**

## **5** Quality Declaration

Table 34 shows the characteristics of the quality parameters in the XMC1100.

Table 34 Quality Parameters

Parameter	Symbol	Limit Values		Unit	Notes
		Min.	Max.		
ESD susceptibility according to Human Body Model (HBM)	V <sub>HBM</sub> SR	_	2000	V	Conforming to EIA/ JESD22-A114-B
ESD susceptibility according to Charged Device Model (CDM) pins	V <sub>CDM</sub> SR	_	500	V	Conforming to JESD22- C101-C
Moisture sensitivity level	MSL CC	_	_	_	JEDEC
• TSSOP-16, TSSOP-38			3		J-STD-020D
• VQFN-24, VQFN-40			1		
Soldering temperature	$T_{\rm SDR}{\rm SR}$	-	260	°C	Profile according to JEDEC
					J-STD-020D

## **Microcontroller Series for Industrial Applications**



## **6 Revision History**

## **6** Revision History

Document revision	Date	Description of changes
V1.8	2016-09	In Absolute Maximum Ratings renamed parameter V <sub>CM</sub> to V <sub>INP2</sub> , as the limitation is related to most P2 pins, also if no ACMP is available. Clarified limit to pins P2.[1,2,6:9,11] in Overload specification.
V1.9	2025-01-22	Updated template. Updated Moisture sensitivity level in Quality Declaration section.

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Edition 2025-01-22 Published by Infineon Technologies AG 81726 Munich, Germany

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Document reference IFX-zyd1719306839235

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